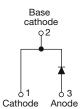
# VS-8ETH06-M3

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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	8 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.3 V				
t <sub>rr</sub> typ.	18 ns				
T <sub>J</sub> max.	175 °C				
Package	TO-220AC 2L				
Circuit configuration	Single				

### FEATURES

Hyperfast Rectifier, 8 A FRED Pt®

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 144 °C	8			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	90	A		
Repetitive peak forward current	I <sub>FM</sub>		16			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	2.0	2.4	V	
		I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	1.3	1.8		
Deverse legions summert		$V_{R} = V_{R}$ rated	-	0.3	50		
Reverse leakage current	I <sub>R</sub>	$T_{\rm J} = 150 ^{\circ}{\rm C},  V_{\rm R} = V_{\rm R}  {\rm rated} - 55$		500	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	17	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_c = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 100$	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V		18	22	
Reverse recevent time	+	$I_F = 8 \text{ A}, dI_F/dt = 100$	) A/µs, V <sub>R</sub> = 30 V	-	20	25	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	25	-	ns
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/µs V <sub>R</sub> = 390 V	-	40	-	
Book receivery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.4	-	A
Peak recovery current		T <sub>J</sub> = 125 °C		-	4.8	-	
	0	T <sub>J</sub> = 25 °C		-	25	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-	ne
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 600 A/μs	-	33	-	ns
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	12	-	А
Reverse recovery charge	Q <sub>rr</sub>		V <sub>R</sub> = 390 V	-	220	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	1.4	2	°C/W	
Thermal resistance, junction-to-ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70		
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-		
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-220AC 2L	8ETH06				

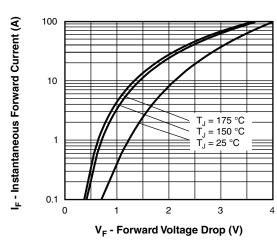


Fig. 1 - Typical Forward Voltage Drop Characteristics

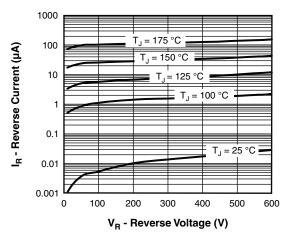


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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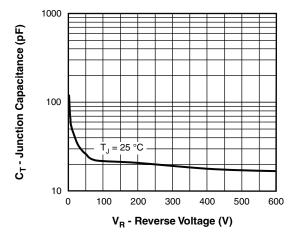


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

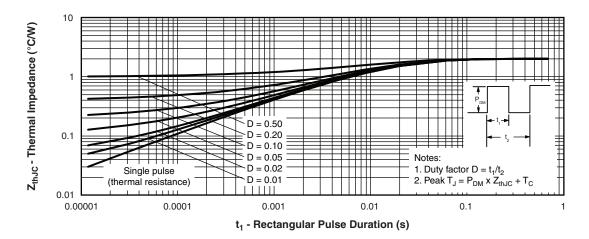
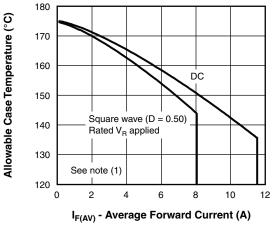
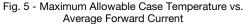


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

Average Power Loss (W)



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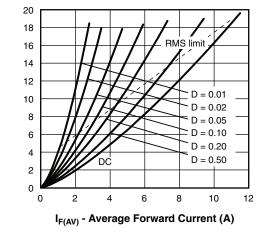


Fig. 6 - Forward Power Loss Characteristics

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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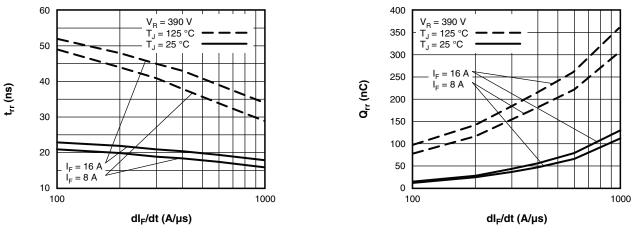
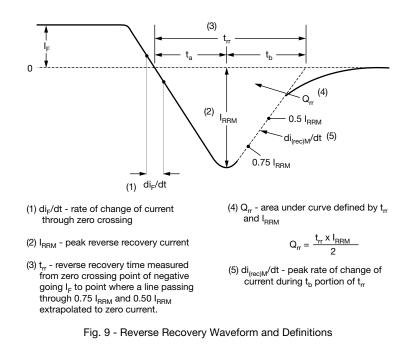


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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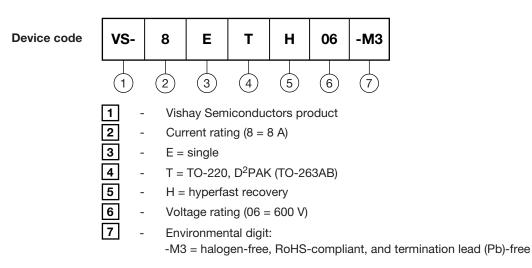






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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION						
VS-8ETH06-M3	50	Antistatic plastic tubes				

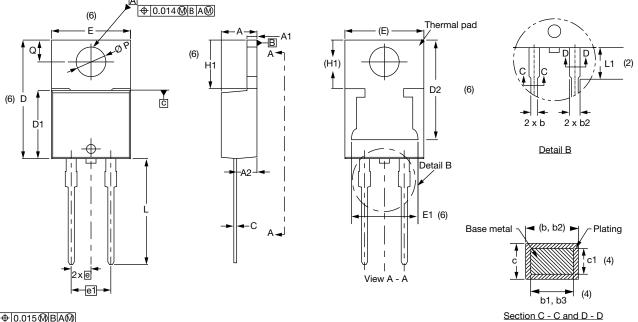
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391			



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**TO-220AC 2L** 

#### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC	® outline TO-220AC

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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